



### AH3769Q

#### HIGH-VOLTAGE, LOW-SENSITIVITY AUTOMOTIVE HALL-EFFECT LATCH

3 OUTPUT

 $1 V_{DD}$ 

### Description

The AH3769Q is an AEC-Q100 qualified high-voltage, low-sensitivity Hall-Effect latch IC designed for brushless DC-motor commutation, speed measurement, angular or linear encoders and position sensors in automotive applications. To support a wide range of demanding applications, the design is optimized to operate over the supply range of 3.0V to 28V. With chopper stabilized architecture and an internal bandgap regulator to provide temperature compensated supply for internal circuits, the AH3769Q provides a reliable solution over the whole operating range. For robustness and protection, the device has a reverse blocking diode with a Zener clamp on the supply. The output has an over current limit and a Zener clamp.

The single, open-drain output can be switched on with South pole of sufficient strength and switched off with North pole of sufficient strength. When the magnetic flux density (B) perpendicular to the package is larger than the operate point ( $B_{op}$ ) the output is switched on (pulled low). The output is held latched until magnetic flux density reverses and becomes lower than the release point ( $B_{rp}$ ).

### **Features**

- Bipolar Latch Operation (South Pole: On, North Pole: off)
- High Sensitivity: B<sub>op</sub> and B<sub>rp</sub> of +220G and -220G Typical
- Single, Open-Drain Output with Overcurrent Limit
- 3.0V to 28V Operating Voltage Range
- Chopper Stabilized Design Provides
  - Superior Temperature Stability
  - Minimal Switch Point Drift
  - Enhanced Immunity to Stress
- Good RF Noise Immunity
- Reverse Blocking Diode
- · Zener Clamp on Supply and Output Pins
- -40°C to +150°C Operating Temperature
- ESD: HBM >8kV, CDM: >2kV
- AEC-Q100 Grade 0 Qualified
- Industry Standard SOT23 and SIP-3 Packages
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Notes:

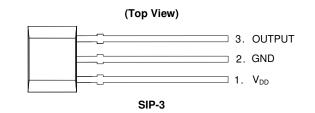
# 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

- See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and</li>
- Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.</li>

#### nd an internal ted supply for

SOT23

(Top View)



## Applications

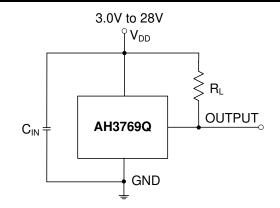
**Pin Assignments** 

GND 2

- Brushless DC-Motor Commutation
- · Revolution Per Minute (RPM) Measurement
- · Angular and Linear Encoder and Position Sensing and Indexing
- Flow Meters
- Contactless Commutation, Speed Measurement and Angular Position Sensing/Indexing in Automotive Applications



# **Typical Applications Circuit**



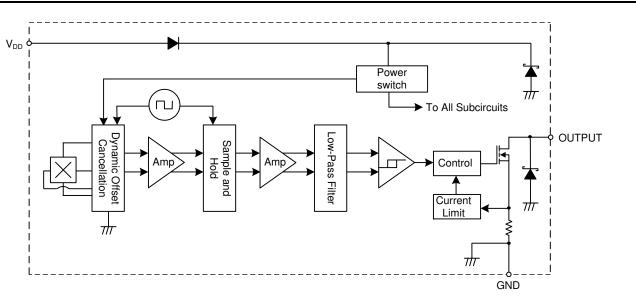
Note: 4. C<sub>IN</sub> is for power stabilization and to strengthen the noise immunity, the recommended capacitance is 10nF ~ 100nF. R<sub>L</sub> is the pull-up resistor.

### **Pin Descriptions**

Package: SOT23 and SIP-3

Pin Number	Pin Name	Function
1	V <sub>DD</sub>	Power Supply Input
2	GND	Ground
3	OUTPUT	Output Pin

# **Functional Block Diagram**





#### Absolute Maximum Ratings (Notes 5 & 6) (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Characteristic		Value	Unit
V <sub>DD</sub>	Supply Voltage (Note 6)		32	V
V <sub>DDR</sub>	Reverse Supply Voltage (Note 6)	-32	V	
V <sub>OUT_MAX</sub>	Output Off Voltage (Note 6)	32	V	
I <sub>OUT</sub>	Continuous Output Current	60	mA	
I <sub>OUT_R</sub>	Reverse Output Current	-50	mA	
В	Magnetic Flux Density	Unlimited	•	
D-	Package Power Dissipation	SIP-3	550	mW
PD	Fackage Fower Dissipation	SOT23	230	11100
Ts	Storage Temperature Range		-65 to +165	°C
TJ	Maximum Junction Temperature		+150	°C
ESD HBM	Electros Static Discharge Withstand - Human Body Model (HMI	8	kV	
ESD MM	Electros Static Discharge Withstand - Machine Model (MM)	800	V	
ESD CDM	Electros Static Discharge Withstand - Charged Device Model (C	CDM)	2	kV

Notes: 5. Stresses greater than the 'Absolute Maximum Ratings' specified above may cause permanent damage to the device. These are stress ratings only; functional operation of the device at these or any other conditions exceeding those indicated in this specification is not implied. Device reliability may be affected by exposure to absolute maximum rating conditions for extended periods of time.

6. The absolute maximum V<sub>DD</sub> of 32V is a transient stress rating and is not meant as a functional operating condition. It is not recommended to operate the device at the absolute maximum rated conditions for any period of time.

#### Recommended Operating Conditions (@T<sub>A</sub> = -40°C to +150°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Rating	Unit
V <sub>DD</sub>	Supply Voltage	Operating	3.0 to 28	V
TA	Operating Temperature Range	Operating	-40 to +150	°C

#### Electrical Characteristics (Notes 7 & 8) (@TA = -40°C to +150°C, VDD = 3V to 28V, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
VOUT_ON	Output On Voltage	$I_{OUT} = 20 \text{mA}, \text{B} > B_{op}$	-	0.2	0.4	V
I <sub>LKG</sub>	Output Leakage Current (when output is off)	$V_{OUT} = 28V, B < B_{rp}, Output off$	-	<0.1	10	μA
I <sub>DD</sub>	Supply Current	Output open, $T_A = +25^{\circ}C$	-	3	3.5	mA
		Output open, T <sub>A</sub> = -40°C to +150°C	-	-	4	mA
		$V_{DD} = -18V, T_A = +25^{\circ}C$	-	0.6	-	μΑ
	Reverse Supply Current	V <sub>DD</sub> = -18V, T <sub>A</sub> = -40°C to +150°C	-	0.6	1,500	μA
IDD_R	Reverse Supply Current	$V_{DD} = -28V, T_A = +25^{\circ}C$	-	1.6	-	μA
		$V_{DD} = -28V, T_A = -40^{\circ}C \text{ to } +150^{\circ}C$	-	1.6	2,500	μA
tp on	Device Power-On Time (start-up time)	$V_{DD} \ge 3V, B > B_{op}$ (Note 7)	-	10		μs
fc	Chopping Frequency	$V_{DD} \ge 3V$	-	800	-	kHz
td	Response Time Delay (time from magnetic threshold reached to the start of the output rise or fall)	(Note 9)	-	3.75	-	μs
tr	Output Rising Time (external pull-up resistor RL and load capacitance dependent)	$R_L = 1k\Omega, C_L = 20pF$	-	0.2	1	μs
t <sub>f</sub>	Output Falling Time (Internal switch resistance and load capacitance dependent)	$R_L = 1k\Omega, C_L = 20pF$	-	0.1	1	μs
IOCL	Output Current Limit	B > B <sub>op</sub> , (Note 10)	30	-	55	mA
Vz	Zener Clamp Voltage	I <sub>DD</sub> = 5mA	28	-	-	V

Notes:

7. When power is initially turned on, VDD must be within its correct operating range (3.0V to 28V) to guarantee the output sampling. The output state is valid after the start-up time of 10µs typical from the operating voltage reaching 3V.

8. Typical values are defined at T<sub>A</sub> = +25°C, V<sub>DD</sub> = 12V. Maximum and minimum values over the operating temperature range is not tested in production but guaranteed by design, process control and characterization.

9. Guaranteed by design, process control and characterization. Not tested in production.

10. The device will limit the output current IOUT to current limit of IOCL.

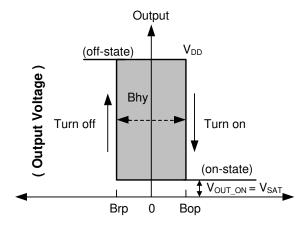


# Magnetic Characteristics (Notes 11 & 12) (T<sub>A</sub> = -40°C to +150°C, V<sub>DD</sub> = 3.0V to 28V, unless otherwise specified.)

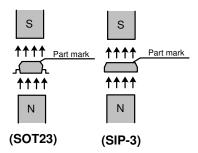
				(	1mT=10 0	Gauss)
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Bops (South pole to part marking side for	Operation Point	$V_{DD} = 12V, T_A = +25^{\circ}C$	-	220	-	
SOT23 and SIP-3 packages)	Operation Foint	$T_A = -40^{\circ}C \text{ to } +150^{\circ}C$	170	220	250	
Brps (North pole to part marking side for	Release Point	$V_{DD} = 12V, T_A = +25^{\circ}C$	-	-220	-	Gauss
SOT23 and SIP-3 packages)	nelease roint	$T_A = -40^{\circ}C \text{ to } +150^{\circ}C$	-250	-220	-170	Gauss
	Hysteresis (Note 13)	$V_{DD} = 12V, T_A = +25^{\circ}C$	-	340	-	
B <sub>hy</sub> ( B <sub>opx</sub>  - B <sub>rpx</sub>  )	Tysteresis (Note 13)	$T_{A} = -40^{\circ}C \text{ to } +150^{\circ}C$	340	440	500	

Notes: 11. When power is initially turned on, VDD must be within its correct operating range (3.0V to 28V) to guarantee the output sampling. The output state is valid after the start-up time of 10µs typical from the operating voltage reaching 3V.

12. Typical values are defined at T<sub>A</sub> = +25°C, V<sub>DD</sub> = 12V. Maximum and minimum values over the operating temperature range is not tested in production but guaranteed by design, process control and characterization. 13. Maximum and minimum hysteresis is guaranteed by design, process control and characterization.









Brp

Brp

150

Brp

150

125

175

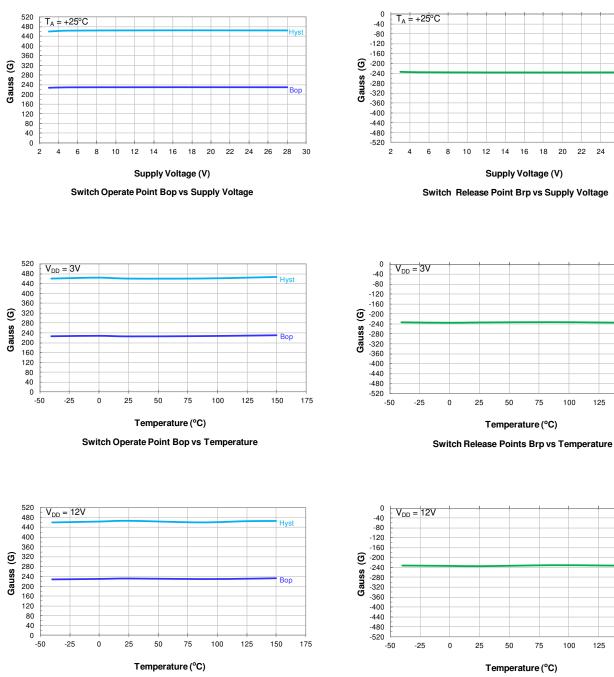
175

125

22 24 26 28 30

# **Typical Operating Characteristics**

#### Output Switch Operate and Release Points (Magnetic Thresholds) – Bop and Brp



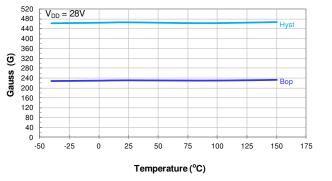
Switch Operate Point Bop vs Temperature



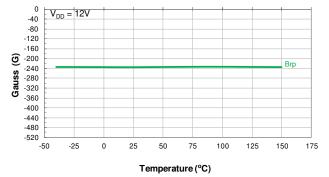


# **Typical Operating Characteristics**

#### Output Switch Operate and Release Points (Magnetic Thresholds) - Bop and Brp (cont.)

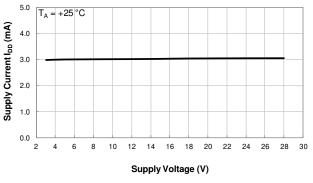


Switch Operate Point Bop vs Temperature

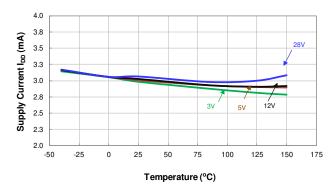




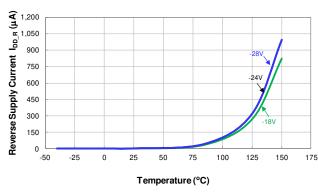
### **Supply Current**



Supply Current vs Supply Voltage

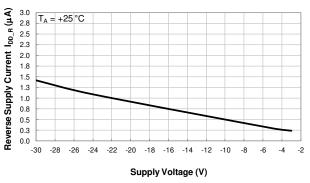


Supply Current vs Temperature



Reverse Supply Current vs Temperature

#### **Reverse Supply Current**

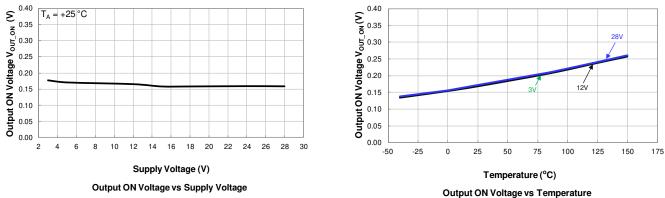


Reverse Supply Current vs Supply Voltage

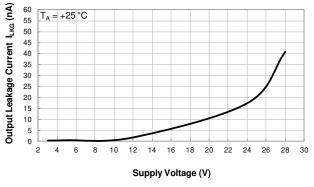


# Typical Operating Characteristics (cont.)

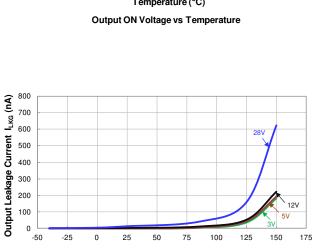
#### **Output Switch On Voltage**



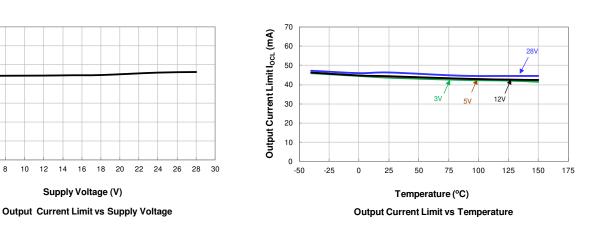
#### **Output Switch Leakage Current**



Output Leakage Current vs Supply Voltage



Temperature (°C) Output Leakage Current vs Temperature



#### **Output Current Limit**

 $T_A = +25 \degree C$ 

70

60

50

40

30

20

10

0

2 4 6

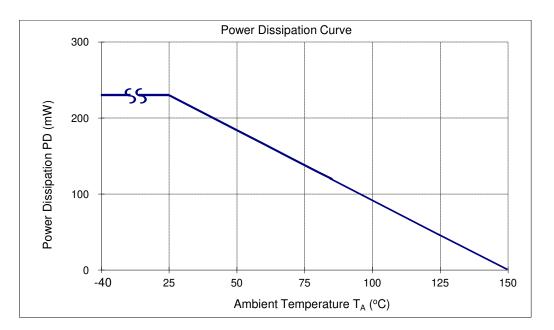
Output Current Limit I<sub>ocL</sub> (mA)



### **Thermal Performance Characteristics**

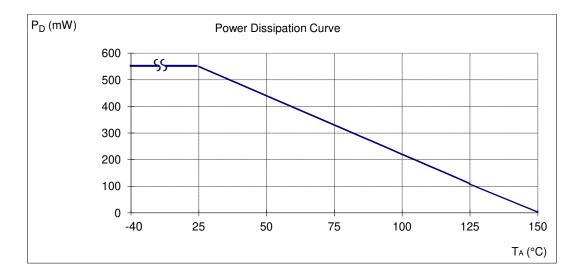
#### (1) Package type: SOT23

T <sub>A</sub> (°C)	25	50	60	70	80	85	90	100	105	110	120	125	130	140	150
P <sub>D</sub> (mW)	230	184	166	147	129	120	110	92	83	74	55	46	37	18	0



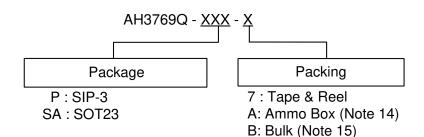
#### (2) Package type: SIP-3

T <sub>A</sub> (°C)	25	50	60	70	80	85	90	100	105	110	120	125	130	140	150
P <sub>D</sub> (mW)	550	440	396	362	308	286	264	220	198	176	132	110	88	44	0





# **Ordering Information**

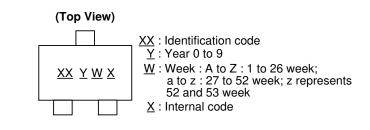


	Package		Bulk		7" Tape an	d Reel	Ammo Box		
Part Number	Code	Packaging	Quantity	Part Number Suffix	Quantity	Part Number Suffix	Quantity	Part Number Suffix	
AH3769Q-P-A	Р	SIP-3	NA	NA	NA	NA	4,000/Box	-A	
AH3769Q-P-B	Р	SIP-3	1,000	-B	NA	NA	NA	NA	
AH3769Q-SA-7	SA	SOT23	NA	NA	3,000/Tape & Reel	-7	NA	NA	

Notes: 14. Ammo Box is for SIP-3 Spread Lead. 15. Bulk is for SIP-3 Straight Lead.

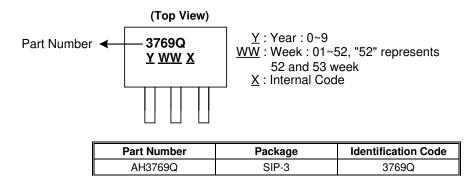
## **Marking Information**

#### (1) Package Type: SOT23



Part Number	Package	Identification Code		
AH3769Q	SOT23	WU		

#### (2) Package Type: SIP-3

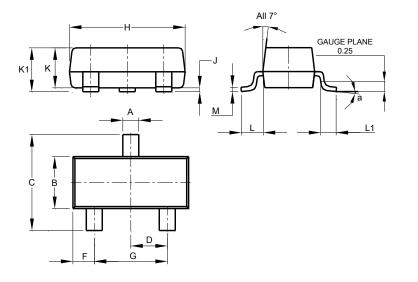




# Package Outline Dimensions (All dimensions in mm.)

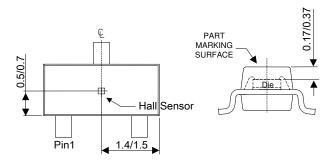
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

#### (1) Package Type: SOT23



	SO	T23	
Dim	Min	Max	Тур
Α	0.37	0.51	0.40
В	1.20	1.40	1.30
С	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
н	2.80	3.00	2.90
J	0.013	0.10	0.05
К	0.890	1.00	0.975
K1	0.903	1.10	1.025
L	0.45	0.61	0.55
L1	0.25	0.55	0.40
М	0.085	0.150	0.110
а		8°	
All	Dimens	ions in	mm

Min/Max



Sensor Location - To be updated

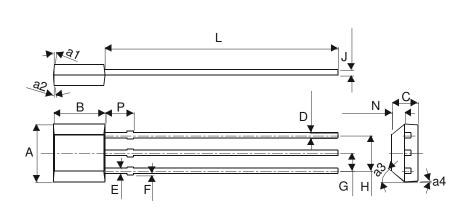


# Package Outline Dimensions (cont.) (All dimensions in mm.)

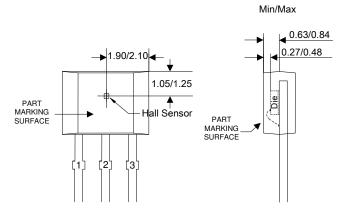
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

#### (2) Package Type: SIP-3 Bulk

Sensor location to be added



	SIP-3 (Bu	lk)
Dim	Min	Max
Α	3.9	4.3
a1	5°	Тур
a2	5°	Тур
a3	45°	' Тур
a4	3°	Тур
В	2.8	3.2
С	1.40	1.60
D	0.33	0.432
E	0.40	0.508
F	0	0.2
G	1.24	1.30
H	2.51	2.57
J	0.35	0.43
L	14.0	15.0
N	0.63	0.84
Р	1.55	-
All Di	mension	s in mm



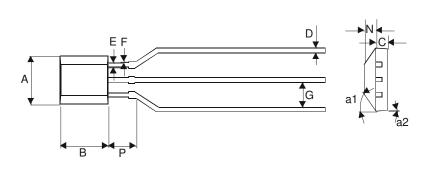
Sensor Location - To be updated



### Package Outline Dimensions (cont.) (All dimensions in mm.)

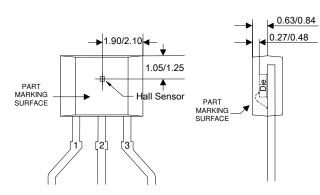
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

#### (3) Package Type: SIP-3 Ammo Pack



SIP-	3 (Amm	o Pack)
Dim	Min	Max
Α	3.9	4.3
a1	45	5° Typ
a2	3	° Тур
в	2.8	3.2
С	1.40	1.60
D	0.35	0.41
ш	0.43	0.48
F	0	0.2
G	2.4	2.9
N	0.63	0.84
Р	1.55	-
All Di	mensio	ns in mm



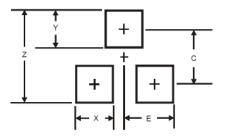


Sensor Location - To be updated

# Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

#### (1) Package Type: SOT23



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
E	1.35



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